



650nm 2mW Laser Diode Module

R650±10–2mWF–03BCK–S



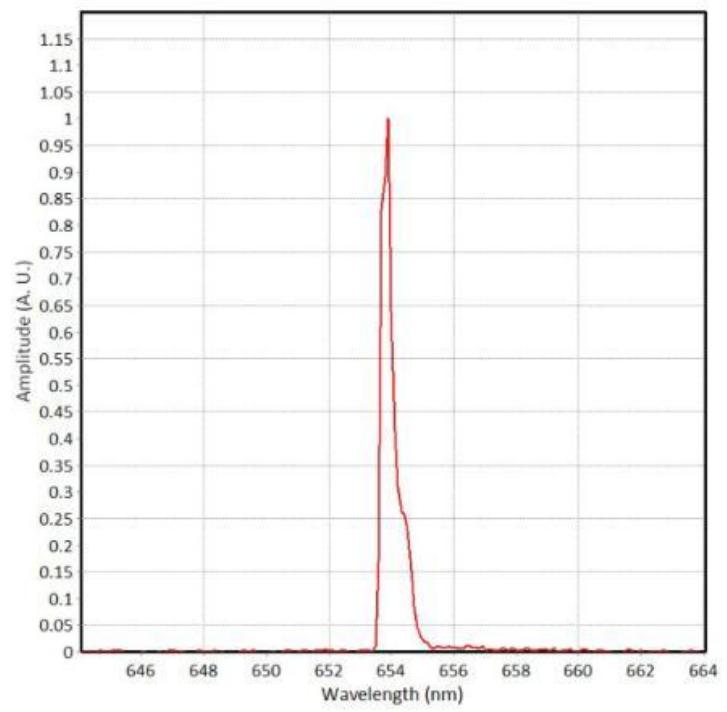
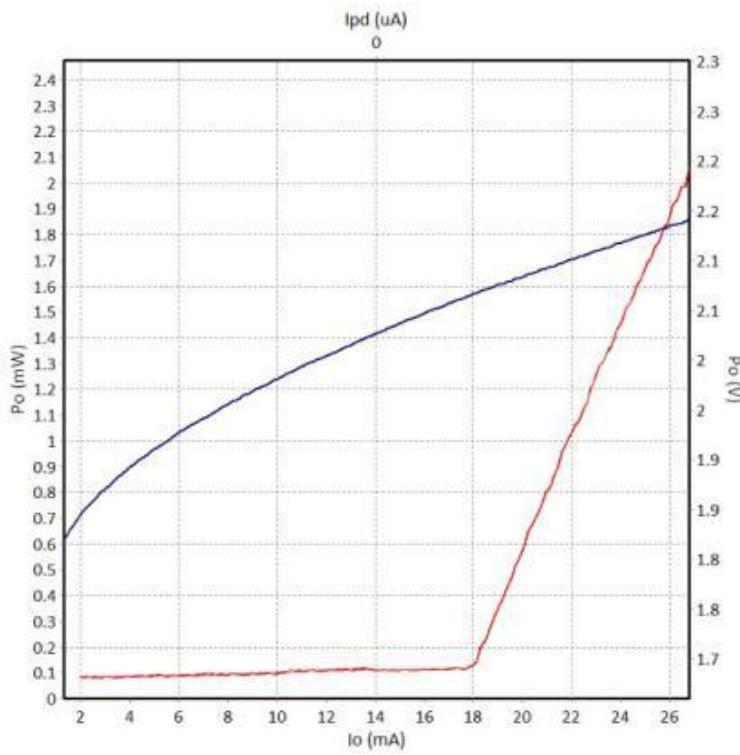
Feature

Output power: 2mW
 Wavelength: 650±10nm
 Fiber core: 4 μ m, 0.13NA

Application

Medical use
 Pilot light
 Holography

650nm 2mW Characteristics (25°C)





Typical Device Performance(25°C)

Parameter		Symbol	Typical Value		Unit
			R650±10-2mWF-03BCK-S		
Optical	CW Output Power	P _{op}	2		mW
	Center Wavelength	λ _c	650±10		nm
	Spectral Width	Δλ	≤3		nm
	Temperature drift of wavelength	Δλ / ΔT	0.3		nm/°C
Electrical	Threshold Current	I _{th}	19		mA
	Operating Current	I _{op}	26		mA
	Operating Voltage	V _{op}	2.3		V
	Slope Efficiency	η _{es}	0.3		W/A
Fiber	Fiber Core Diameter	d _{core}	4		μm
	Fiber Clad Diameter	d _{clad}	125		μm
	Fiber Buffer Diameter	d _{buffer}	250		μm
	Numerical Aperture	NA	0.13		-
	Connector	-	FC/PC,ST,SMA905		-

Other Parameters

Parameter	Operating Temperature /°C	Operating Relative Humidity /%	Storage Temperature /°C	Storage Relative Humidity /%	Lead Soldering Temperature (max/°C)
Min	10	-	-20	-	-
Max	30	75	70	90	250(10Sec.)

Package Dimensions (mm)

Pin	Function
1	Laser(-)
2	Laser(+); PD (N)
3	PD (P)

